

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

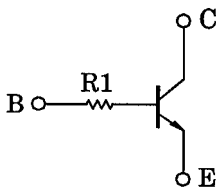
RN1312,RN1313

Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

Unit: mm

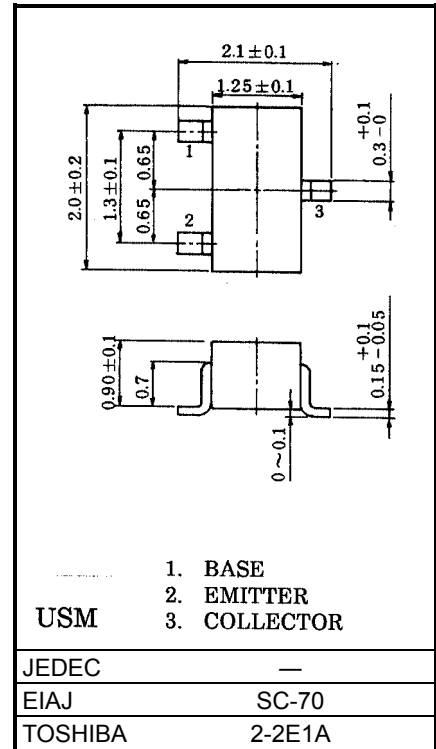
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2312, RN2313

Equivalent Circuit



Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	100	mA
Base current	I_B	100	mA
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	125	°C
Storage temperature range	T_{stg}	-55~125	°C



1. BASE
2. EMITTER
3. COLLECTOR

USM

JEDEC

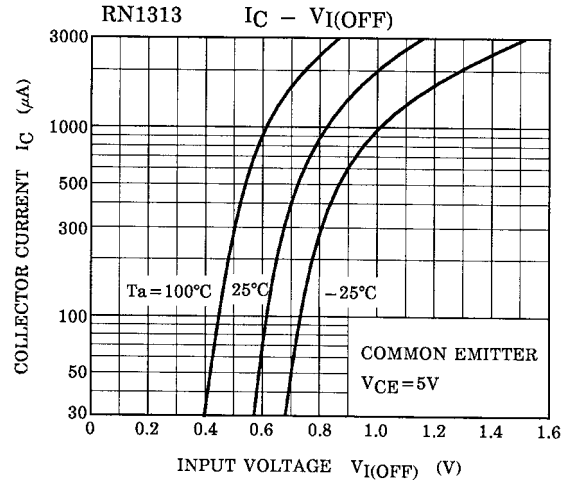
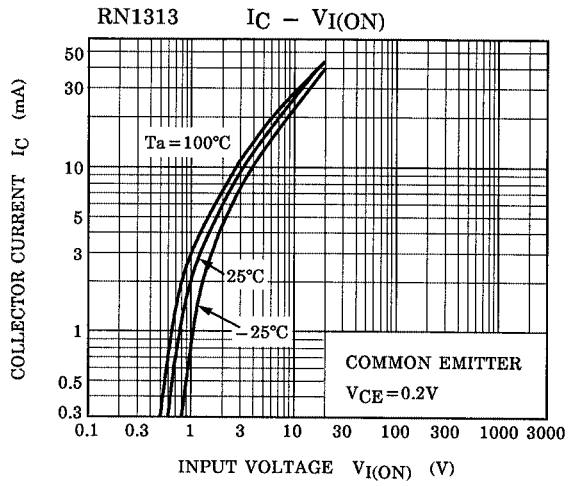
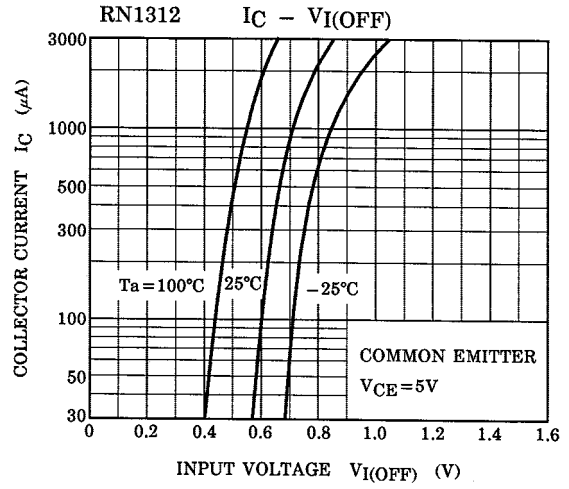
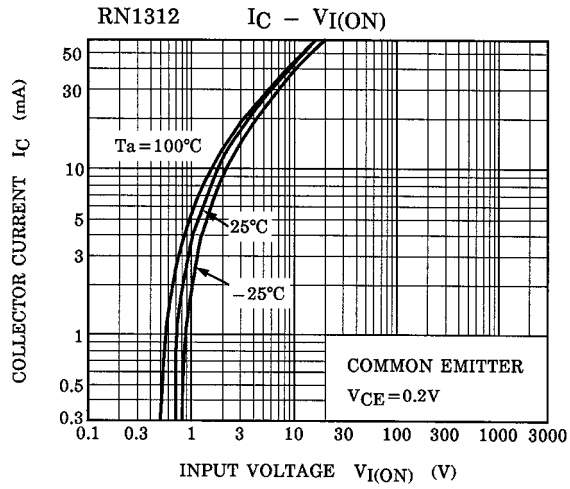
EIAJ SC-70

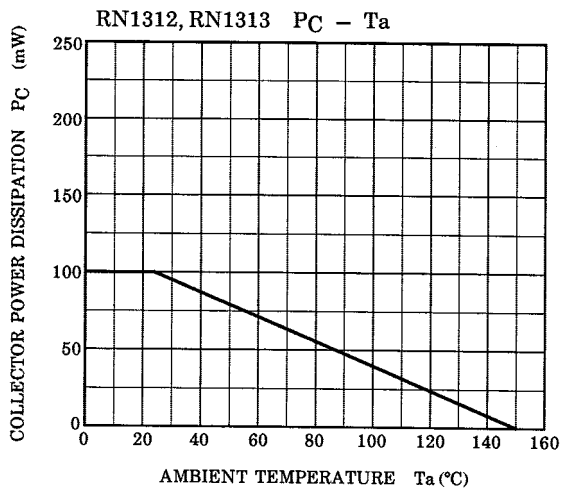
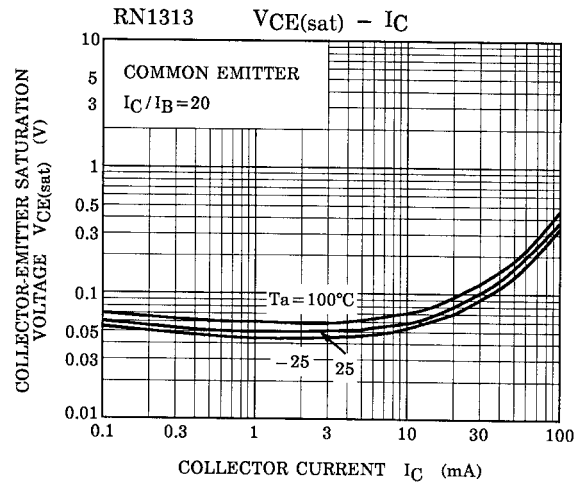
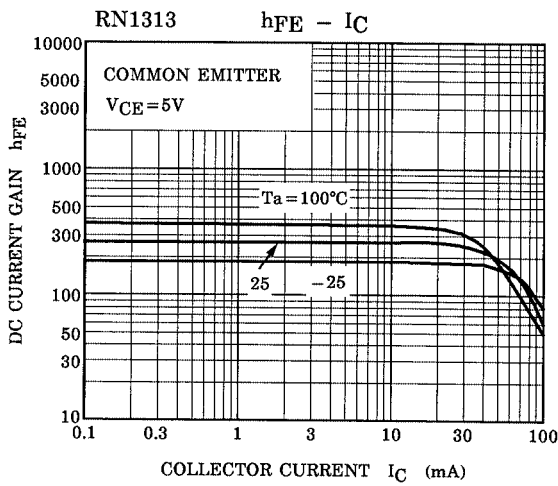
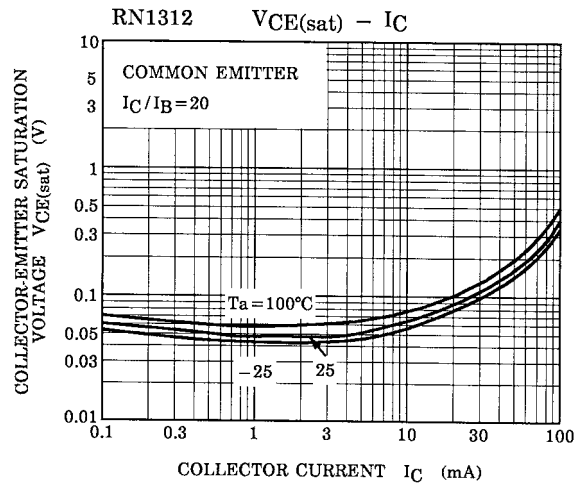
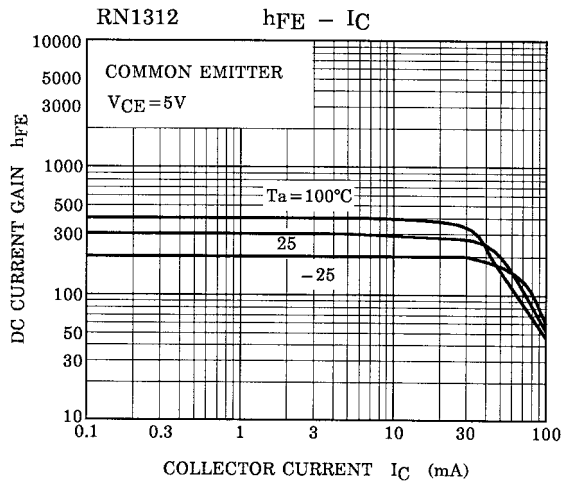
TOSHIBA 2-2E1A

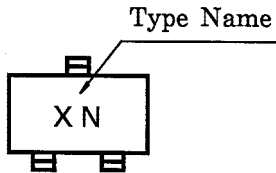
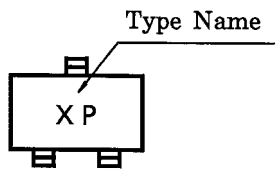
Weight: 0.006g

Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	—	$V_{CB} = 50V, I_E = 0$	—	—	100	nA
Emitter cut-off current	I_{EBO}	—	$V_{EB} = 5V, I_C = 0$	—	—	100	nA
DC current gain	h_{FE}	—	$V_{CE} = 5V, I_C = 1mA$	120	—	700	
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	$I_C = 5mA, I_B = 0.25mA$	—	0.1	0.3	V
Transition frequency	f_T	—	$V_{CE} = 10V, I_C = 5mA$	—	250	—	MHz
Collector output capacitance	C_{ob}	—	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	3	6	pF
Input resistor	RN1312	R1	—	15.4	22	28.6	kΩ
	RN1313			32.9	47	61.1	





Type Name	Marking
RN1312	
RN1313	

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